measurement Systems 2013 ko

Question 1

AMCIOZIS static characte	enistics:
operating temperature	-55°C to 150°C
Input Range	-6 gauss to 6 gauss
Linearity	± 1.6% F5
Hysteresis	± 0.08% FS
Bridge Offset	11.25 mV
Sensitivity	1.25 mV/V/gauss
Noise Density	48 nV/V#2
Resolution	85 pageniss
Sensitivity Temperature Coefficient	-0.32%/€
Bridge Offset Temperature Coefficient	26.05%/0
Bridge Ohmic Temperature Coefficie	
Cross-Axis Effect	0.3 % FS

LMV324N Static Characteristics	
offset Voltage (input)	9 mV
Bias Current	SOO NA
Offset current (input)	150 nA
CMRR	65 dB
PSRR	60 dB
Output Swing	400mV

*There is a fundamental error with the Circuit shown in Figure 6 in that it can only have an input range of ±2.5 years. There are two ways I could address this problem:

D'Limit the system specifications to = 2.5 gauss.

z) Change resistors R5 and R6
to reduce the gain to allow
for ±5 gayss.

I'll go with option 2: R5-R6=10E52±0.5%

System Input Range ±5 gauss
System Operating Temperature 15°C to 25°C

Error Due to HMC10215:

Resolution = 85/1 yauss > 5 × 100% = 0.0017% FS

Bridge Offset = 11.25 mV =) 5V = 22.5% FS

Sensitivity error = 1-25-1 x 100%= 25% FS table shows

Noise deusity = 48x10-9 × 10000 = 4.8x10-6v => 0.0096 % FS

Linearity = 1.6% FS

Hysteresis = 0.08% FS

Sensitivity Temperature coefficient: $\Delta T = 25^{\circ}c - 15^{\circ}c$ = -0.32% (10)

Bridge offset temperature coefficient: 0.05% (10) = 0.5%

Cross-Axis ARCt = 0.3% FS

MADE A Pridge Offset recolation noise linearly hypersis to accept the 225 (1.005) A c. accept to accept the periodic drift

Ideal Straight line:

V= 50x | mV/V/gguss (7)

Introducing error

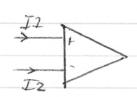
 $V_{o}(y) = \begin{bmatrix} (1 - 0.032) & (1 - 0.032) & (1 + 0.000017) & (1 + 0.000017) \\ (1 + 0.016 + 0.0008 + 0.003) & (1 + 0.0003) & (1 + 0.0008 + 0.003) \end{bmatrix}$ $\frac{1 + 0.016 + 0.0008 + 0.003}{1 + 0.0008 + 0.003}$

FS @ 8 = 5 gamss

ideally Vo=25mV

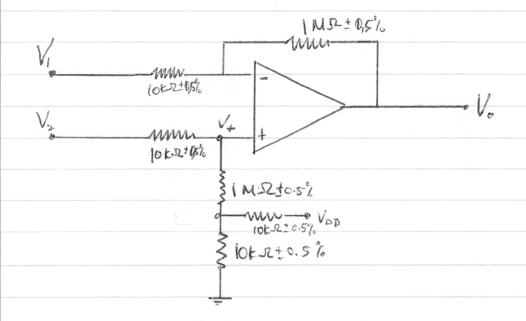
Actually: error = 4463 %

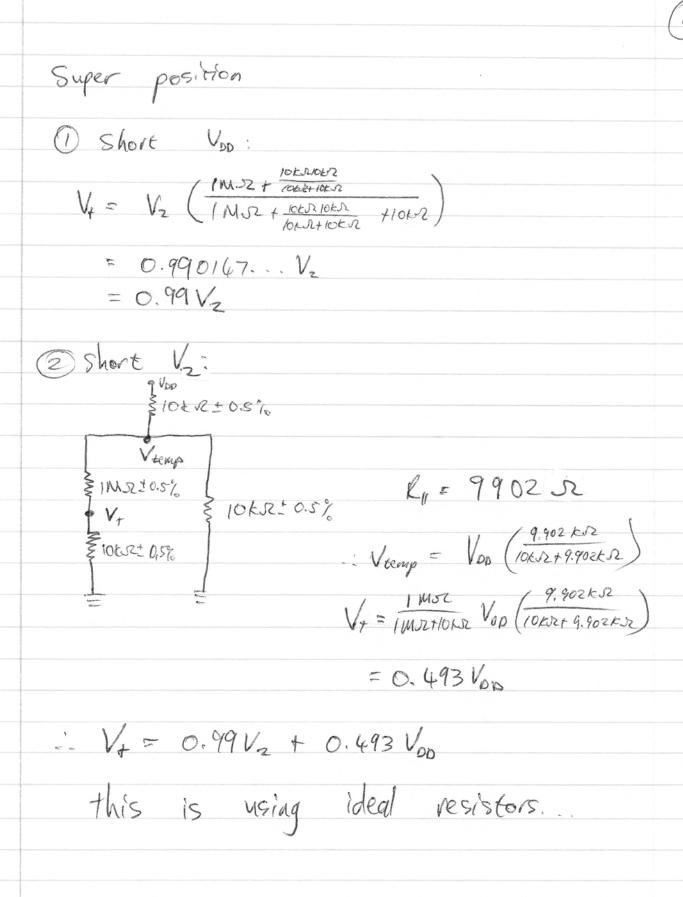
Error due to Amp:



$$I_{\text{Bias}} = I_1 + I_2$$
 $I_{\text{offset}} = I_1 - I_2$

IZ= 575 nA 2 considering we're working
IZ= 425 nA) with mV these may
be significant.





So the output would be:

V1 - V+ = V+ - V0 10KJZ 1MJZ

 $100(V_1-V_4)-V_4=-V_6$

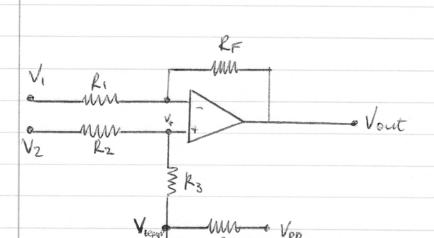
 $V_0 = 100(V_4 - V_1) + V_4$

= 101V+-100V,

= 99.99 V2 + 49.783 V00 - 100V, (Ideally)

So at full scale we have Vi=5mV and Vz=0mV

· · Vo =



Superposition for
$$V_{+}$$
:

Now $V_{+} = \left(V_{2} - V_{temp}\right) \left(\frac{R_{3}}{R_{2} + R_{3}}\right)$

$$= \left(V_{2} - V_{DD}/2\right) \left(\frac{R_{3}}{R_{2} + R_{3}}\right)$$

$$V_{out} = \left(V_2 - \frac{V_{on}}{2}\right) \left(1 + \frac{R_F}{R_1}\right) \left(\frac{R_3}{R_2 + R_3}\right) - \frac{R_F}{R_1} V_1$$

$$= 100 \left(V_2 - \frac{V_{oo}}{2}\right) - 100 V_1$$

From A.3.10 TI Op amps for Everyone

= 100 V2 + Vtemp - 100 V

I know max difference is 25mV : V2-V, = 25mV (ideally)

Introducing errors

Make RF big R Small R3 big Assuming We're at 15°C and resistors have

RF = 1M52 (1.005)(1+25×10-6 Zero temp drift@ 25 R= 1MJZ(1+0.005 = 25×10-6×10) = 1.00475 MJZ L= 10KR (1-0.005= 25×10-6×10) = 9.9475 KSZ Rz= 9,9475 KD Rz = 1.00475MJZ Now Vo= 101.005 V2 + Very - 101.005 V, = 101.005 (V2-V,) + Vemp

Introduce dup errors

V= 101.005 (Vz-V,) + Very (1.01) + 9mV x 101.005

@V2-V, = 25mV x 1.4463

18	3
10	

V=101.005 x25mvx1.4463 + 5x101 + 9mVX101.005

= 7.086 V (Assuming the amp doesn't would)

error = 7.086-5 x 100%

= 41.72%

Entire gystem is 41.72 %

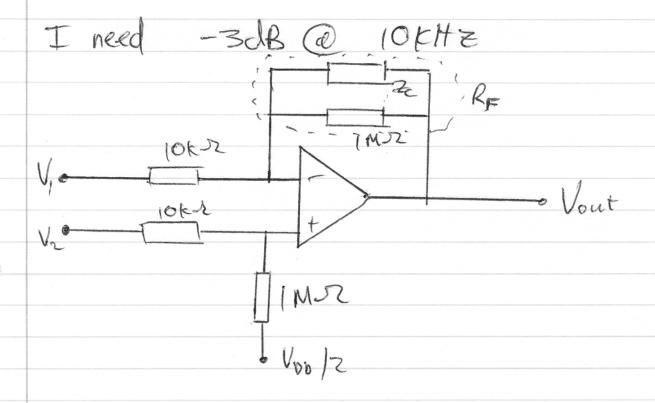
just amp ne use V, -V2 = 25 mV

-- No= 101.005 x 25mV + 5x1.01 + 9mVx101,005

= 5,95917 V

error = 19.18 %

Question Z



I need
$$-3dB$$
 @ $10kHz$

$$-3dB = zo(og(ze))$$
ie when $Gain = \overline{vz}$

